NSN 5961-01-541-0982

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-541-0982 **Inclosure Material:** Plastic **Overall Length:** Between 0.260 inches and 0.280 inches **Overall Height:** Between 0.075 inches and 0.095 inches **Overall Width:** Between 0.220 inches and 0.245 inches **Mounting Method:** Terminal **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 14.4 breakover voltage, dc and 15.9 breakover voltage, dc **Current Rating Per Characteristic:** 139.40 amperes drain current **Product Name:** Diode, transient absorption zener, undirectional and bidirectional, surface mount **Terminal Type And Quantity:** 2 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:** No